

$V_R$	650V
$I_F$	10A
$Q_C$	15nC

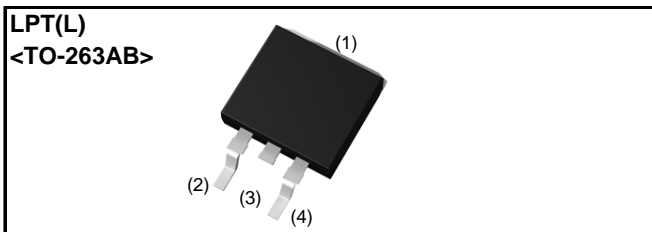
### ●Features

- 1) AEC-Q101 qualified
- 2) Low forward voltage
- 3) Negligible recovery time/current
- 4) Temperature independent switching behavior

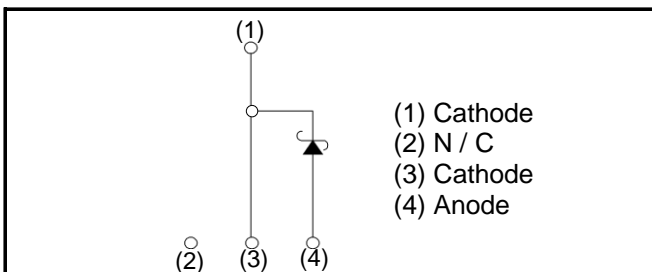
### ●Applications

- On Board Charger
- DC/DC Converter
- Wireless Charger
- EV Charger

### ●Outline



### ●Inner circuit



### ●Packaging specifications

Type	Packaging	Embossed tape
	Reel size (mm)	330
	Tape width (mm)	24
	Basic ordering unit (pcs)	1 000
	Packing code	TLL
	Marking	SCS210AJ

### ●Absolute maximum ratings ( $T_j = 25^\circ\text{C}$ )

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		$V_{RM}$	650	V
Reverse voltage (DC)		$V_R$	650	V
Continuous forward current ( $T_c = 137^\circ\text{C}$ )		$I_F$	10	A
Surge non-repetitive forward current	PW=10ms sinusoidal, $T_j=25^\circ\text{C}$	$I_{FSM}$	38	A
	PW=10ms sinusoidal, $T_j=150^\circ\text{C}$		30	A
	PW=10μs square, $T_j=25^\circ\text{C}$		150	A
Repetitive peak forward current		$I_{FRM}$	45 <sup>*1</sup>	A
$i^2t$ value	PW=10ms, $T_j=25^\circ\text{C}$	$\int i^2 dt$	7.2	A <sup>2</sup> s
	PW=10ms, $T_j=150^\circ\text{C}$		4.5	A <sup>2</sup> s
Total power dissipation		$P_D$	83 <sup>*2</sup>	W
Junction temperature		$T_j$	175	°C
Range of storage temperature		$T_{stg}$	-55 to +175	°C

<sup>\*1</sup>  $T_c=100^\circ\text{C}$ ,  $T_j=150^\circ\text{C}$ , Duty cycle=10% <sup>\*2</sup>  $T_c=25^\circ\text{C}$

**●Electrical characteristics** ( $T_j = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
DC blocking voltage	$V_{DC}$	$I_R = 2.0\text{mA}$	650	-	-	V
Forward voltage	$V_F$	$I_F = 10\text{A}, T_j = 25^\circ\text{C}$	-	1.35	1.55	V
		$I_F = 10\text{A}, T_j = 150^\circ\text{C}$	-	1.55	-	V
		$I_F = 10\text{A}, T_j = 175^\circ\text{C}$	-	1.63	-	V
Reverse current	$I_R$	$V_R = 600\text{V}, T_j = 25^\circ\text{C}$	-	2	200	$\mu\text{A}$
		$V_R = 600\text{V}, T_j = 150^\circ\text{C}$	-	30	-	$\mu\text{A}$
		$V_R = 600\text{V}, T_j = 175^\circ\text{C}$	-	70	-	$\mu\text{A}$
Total capacitance	C	$V_R = 1\text{V}, f = 1\text{MHz}$	-	360	-	pF
		$V_R = 600\text{V}, f = 1\text{MHz}$	-	37	-	pF
Total capacitive charge	$Q_C$	$V_R = 400\text{V}, di/dt = 350\text{A}/\mu\text{s}$	-	15	-	nC
Switching time	$t_C$	$V_R = 400\text{V}, di/dt = 350\text{A}/\mu\text{s}$	-	15	-	ns

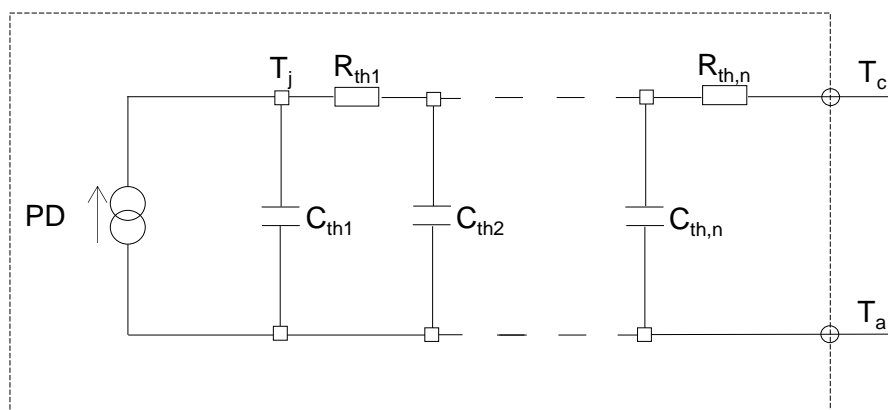
**●Thermal characteristics**

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance	$R_{th(j-c)}$	-	-	1.5	1.8	$^\circ\text{C}/\text{W}$

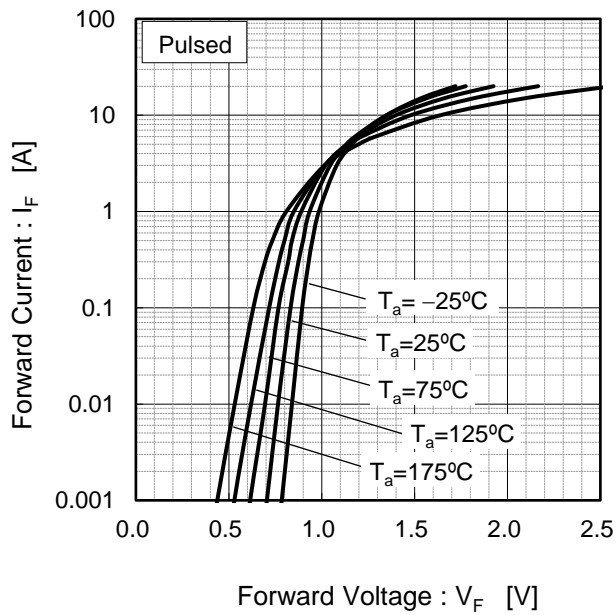
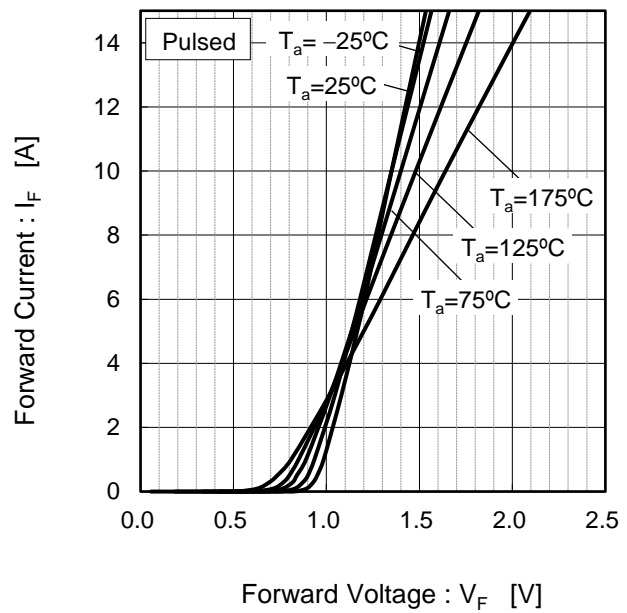
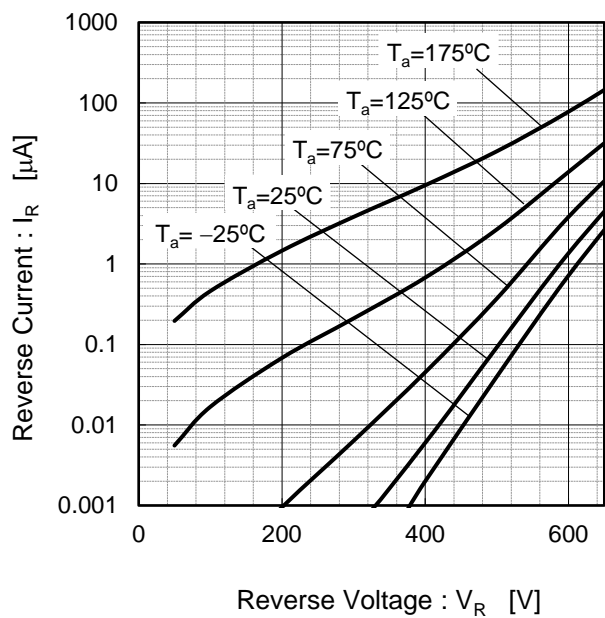
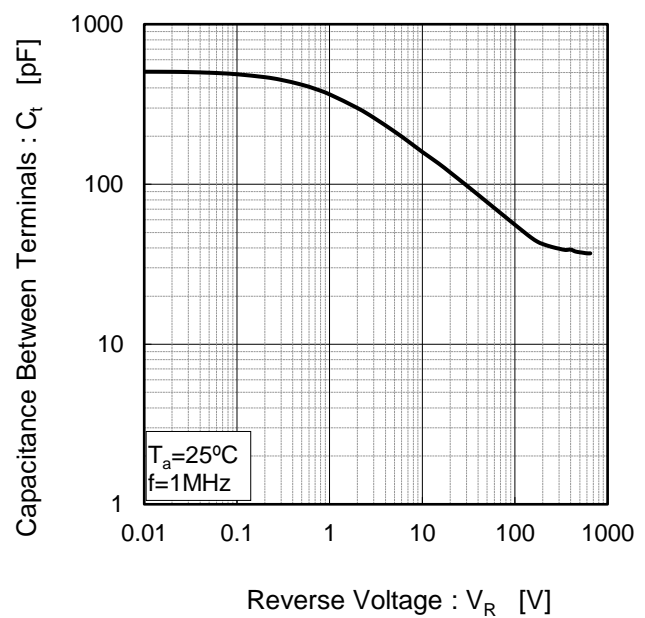
**●Typical Transient Thermal Characteristics**

Symbol	Value	Unit
$R_{th1}$	5.01E-02	K/W
$R_{th2}$	1.14E+00	
$R_{th3}$	3.10E-01	

Symbol	Value	Unit
$C_{th1}$	1.43E-03	Ws/K
$C_{th2}$	8.50E-04	
$C_{th3}$	1.14E-01	



# ●Electrical characteristic curves

Fig.1  $V_F - I_F$  CharacteristicsFig.2  $V_F - I_F$  CharacteristicsFig.3  $V_R - I_R$  CharacteristicsFig.4  $V_R - C_t$  Characteristics

# ●Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

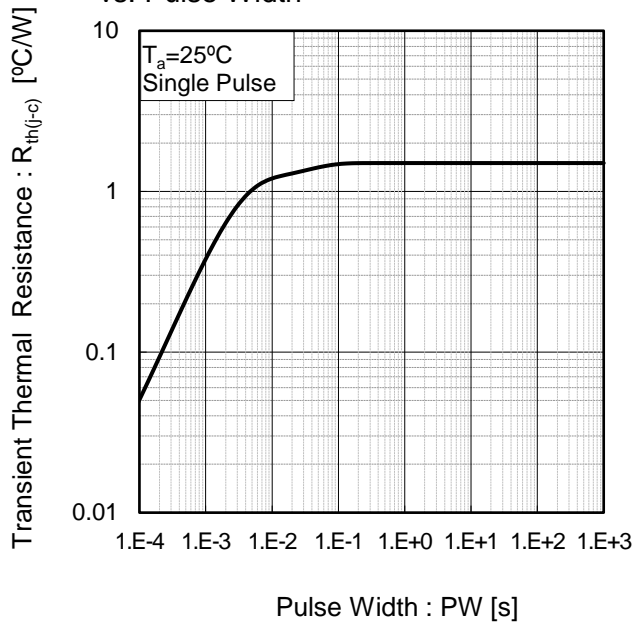


Fig.6 Power Dissipation

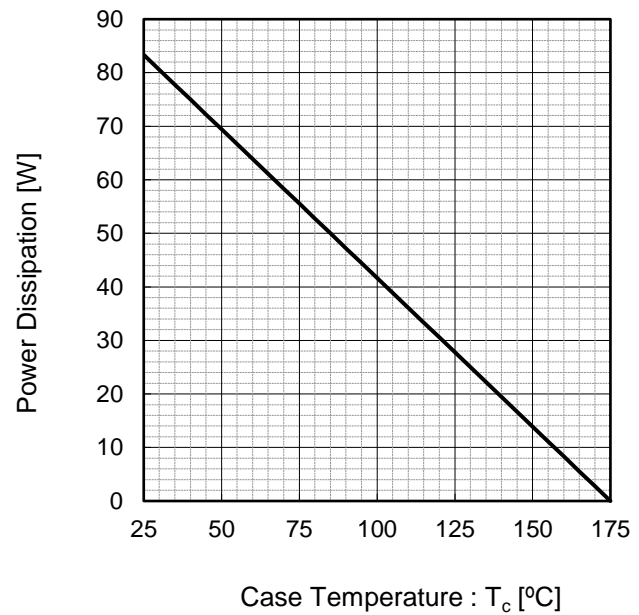
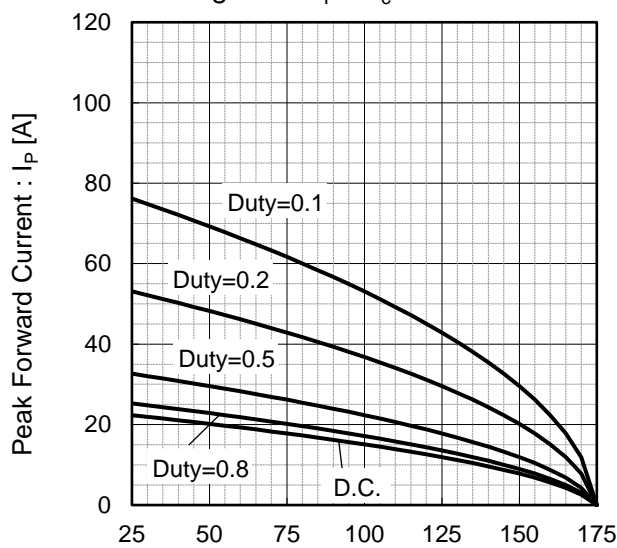


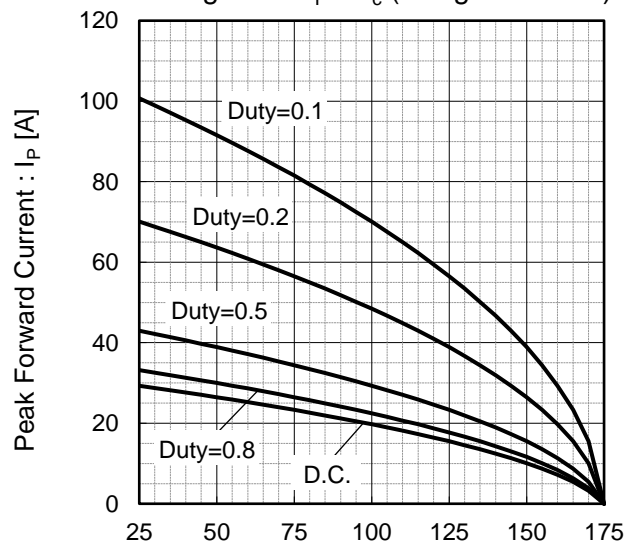
Fig.7\*3 Maximum peak forward current derating curve  $I_P - T_c$



Case Temperature :  $T_c$  [°C]

\*3 Based on max  $V_f$ , max  $R_{th(j-c)}$   
Valid for switching of above 10kHz,  
excluding D.C. curve.

Fig.8\*4 Typical peak forward current derating curve  $I_P - T_c$  (Not guaranteed)



Case Temperature :  $T_c$  [°C]

\*4 Based on typ  $V_f$ , typ  $R_{th(j-c)}$   
Typical value, not guaranteed  
Valid for switching of above 10kHz,  
excluding D.C. curve

## ●Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

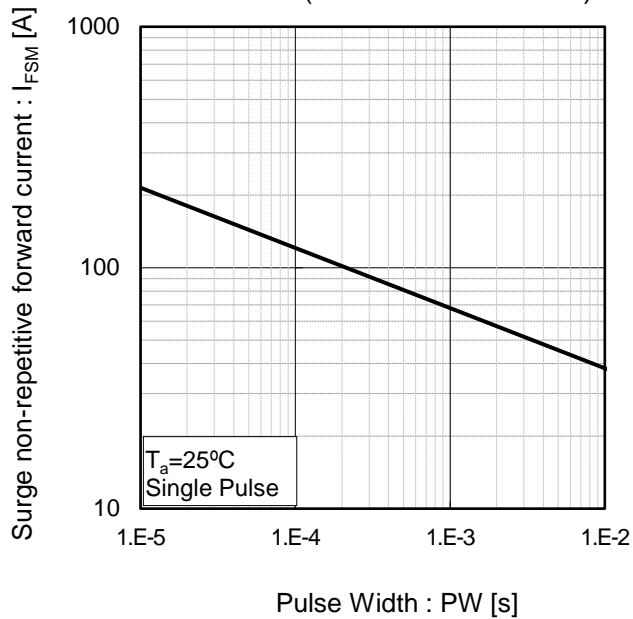
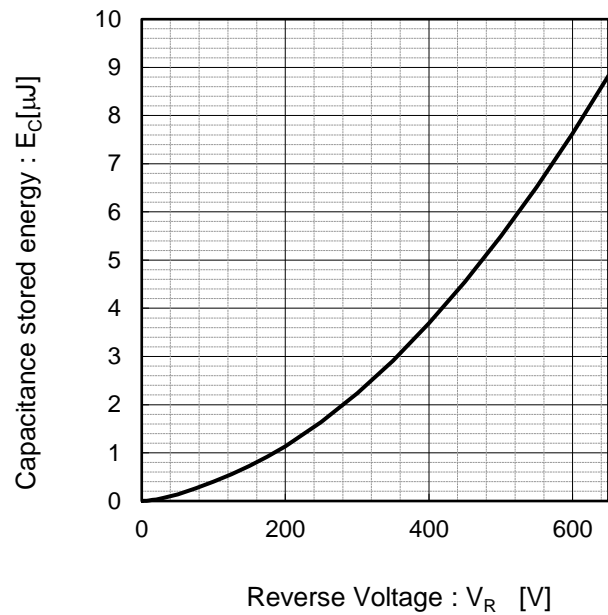
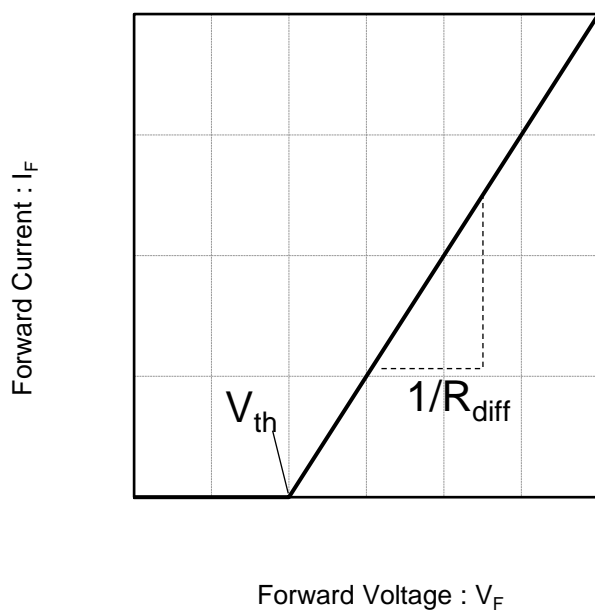


Fig.10 Typical capacitance store energy



## ●Simplified forward characteristic model

Fig.11 Equivalent forward current curve



$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th}(T_j) = a_0 + a_1 T_j$$

$$R_{diff}(T_j) = b_0 + b_1 T_j + b_2 T_j^2$$

Symbol	Typical Value	Unit
$a_0$	9.35E-01	V
$a_1$	-1.12E-03	V/°C
$b_0$	3.98E-02	Ω
$b_1$	1.02E-04	Ω/°C
$b_2$	1.08E-06	Ω/°C <sup>2</sup>

$T_j$  in °C; -55 °C <  $T_j$  < °C ;  $I_F$  < 20 A

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